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### **FJN3308R**

# Switching Application (Bias Resistor Built In) - Switching circuit, Inverter, Interface circuit, Driver Circuit

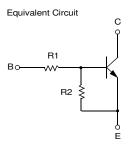
- Built in bias Resistor ( $R_1$ =47K $\Omega$ ,  $R_2$ =22K $\Omega$ )
- Complement to FJN4308R



## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

| Symbol           | Parameter                   | Value     | Units |
|------------------|-----------------------------|-----------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage      | 50        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage   | 50        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage        | 10        | V     |
| I <sub>C</sub>   | Collector Current           | 100       | mA    |
| P <sub>C</sub>   | Collector Power Dissipation | 300       | mW    |
| T <sub>J</sub>   | Junction Temperature        | 150       | °C    |
| T <sub>STG</sub> | Storage Temperature         | -55 ~ 150 | °C    |



### $\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \textbf{unless otherwise noted}$

| Symbol                         | Parameter                            | Test Condition                                      | Min. | Тур. | Max. | Units |
|--------------------------------|--------------------------------------|---|------|------|------|-------|
| BV <sub>CBO</sub>              | Collector-Base Breakdown Voltage     | $I_{C}=10\mu A, I_{E}=0$                            | 50   |      |      | V     |
| BV <sub>CEO</sub>              | Collector-Emitter Breakdown Voltage  | $I_{C}=100\mu A, I_{B}=0$                           | 50   |      |      | V     |
| I <sub>CBO</sub>               | Collector Cut-off Current            | $V_{CB}=40V$ , $I_{E}=0$                            |      |      | 0.1  | μΑ    |
| h <sub>FE</sub>                | DC Current Gain                      | V <sub>CE</sub> =5V, I <sub>C</sub> =5mA            | 56   |      |      |       |
| V <sub>CE</sub> (sat)          | Collector-Emitter Saturation Voltage | I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA         |      |      | 0.3  | V     |
| f <sub>T</sub>                 | Current Gain Bandwidth Product       | I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA         |      | 250  |      | MHz   |
| C <sub>ob</sub>                | Output Capacitance                   | V <sub>CB</sub> =10V, I <sub>E</sub> =0<br>f=1.0MHz |      | 3.7  |      | pF    |
| V <sub>I</sub> (off)           | Input Off Voltage                    | V <sub>CE</sub> =5V, I <sub>C</sub> =100μA          | 0.8  |      |      | V     |
| V <sub>I</sub> (on)            | Input On Voltage                     | $V_{CE}=0.3V$ , $I_{C}=2mA$                         |      |      | 4    | V     |
| R <sub>1</sub>                 | Input Resistor                       |   | 32   | 47   | 62   | ΚΩ    |
| R <sub>1</sub> /R <sub>2</sub> | Resistor Ratio                       |   | 1.9  | 2.1  | 2.4  |       |

# **Typical Characteristics**

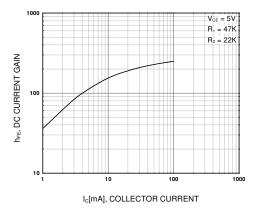


Figure 1. DC current Gain

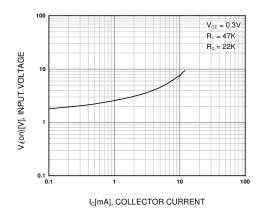


Figure 2. Input On Voltage

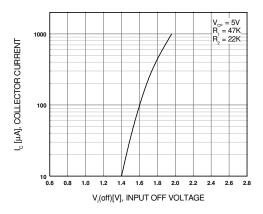


Figure 3. Input Off Voltage

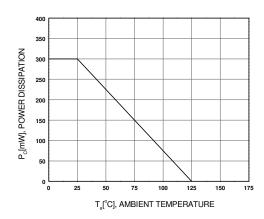
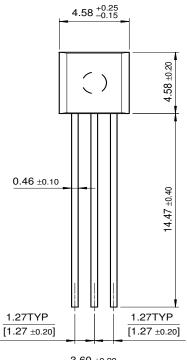
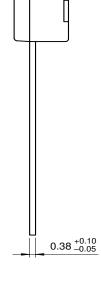
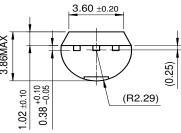


Figure 4. Power Derating

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| DOME™                      | GlobalOptoisolator™ | MICROWIRE™             | QS™                      | SyncFET™        |
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| E <sup>2</sup> CMOS™       | HiSeC™              | MSXPro™                | Quiet Series™            | TruTranslation™ |
| EnSigna™                   | I <sup>2</sup> C™   | OCX™                   | RapidConfigure™          | UHC™            |
| Across the board.          | Around the world.™  | OCXPro™                | RapidConnect™            | UltraFET®       |
| The Power Franchise™       |                     | OPTOLOGIC <sup>®</sup> | SILENT SWITCHER®         | VCX™            |
| Programmable Active Droop™ |                     | OPTOPLANAR™            | SMART START™             |                 |

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Rev. I1

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|--------------------------|---------------------------|---|
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